International **IGR** Rectifier

Series PVT322
Microelectronic Power IC
HEXFET® Power MOSFET Photovoltaic Relay
Dual Pole, Normally Open
0-250V, 170mA AC/DC

General Description

The PVT322 Series Photovoltaic Relay is a dual-pole, normally open solid-state relay that can replace electromechanical relays in many applications. It utilizes International Rectifier's HEXFET power MOSFET as the output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

Series PVT322 Relays are packaged in an 8-pin, molded DIP package with either through-hole or surface mount (gull-wing) terminals. It is available in standard plastic shipping tubes or on tape-and-reel. Please refer to Part Identification information opposite.

Applications

- On/Off Hook switch
- Tip and Ring Line switching
- General switching

Features

- HEXFET Power MOSFET output
- Bounce-free operation
- 4,000 V_{RMS} I/O isolation
- Linear AC/DC operation
- Solid-State Reliability
- UL recognized and BABT certified
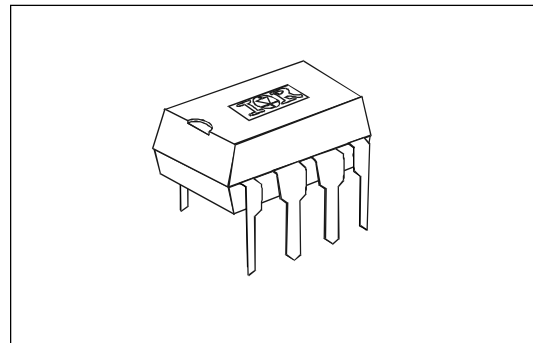
Part Identification

PVT322   thru-hole
PVT322S   SMT
PVT322S-T   SMT, T&R

(HEXFET is the registered trademark for International Rectifier Power MOSFETs)

Series PVT322

Electrical Specifications (-40°C $\leq T_A \leq$ +85°C unless otherwise specified)

INPUT CHARACTERISTICS	Limits	Units
Minimum Control Current (See figure1)	2.0	mA
Maximum Control Current for Off-State Resistance @TA=+25°C	0.4	mA
Control Current Range (Caution: current limit input LED, see figure 5)	2.0 to 25	mA
Maximum Reverse Voltage	7.0	V

OUTPUT CHARACTERISTICS	Limits	Units
Operating Voltage Range	0 to ±250	$V_{(DC\ or\ AC\ peak)}$
Maximum Load Current @ T_A=+40°C 5mA Control (See figure 1) (single and dual channel operation)	170	mA
Maximum Peak Load Current (10ms maximum duration) (single and dual channel operation)	500	mA
Maximum On-State Resistance @T_A=+25°C For 50mA Pulsed load, 5mA Control (see figure 3)	10	Ω
Maximum Off-State Leakage @T_A=+25°C, ±250V (see figure 4)	1.0	µA
Maximum Turn-On Time @T_A=+25°C (see figure 6) For 50mA, 100 V_{DC} load, 5mA Control	3.0	ms
Maximum Turn-Off Time @T_A=+25°C (see figure 6) For 50mA, 100 V_{DC} load, 5mA Control	0.5	ms
Maximum Output Capacitance @ 50V_{DC}	50	pF

GENERAL CHARACTERISTICS	Limits	Units
Minimum Dielectric Strength, Input-Output	4000	V_{RMS}
Minimum Dielectric Strength, Pole-to-Pole	1000	V_{DC}
Minimum Insulation Resistance, Input-Output, @T_A=+25°C, 50%RH, 100V_{DC}	10^{12}	Ω
Maximum Capacitance, Input-Output	1.0	pF
Maximum Pin Soldering Temperature (10 seconds maximum)	+260	
Ambient Temperature Range: Operating	-40 to +85	°C
Storage	-40 to +100	

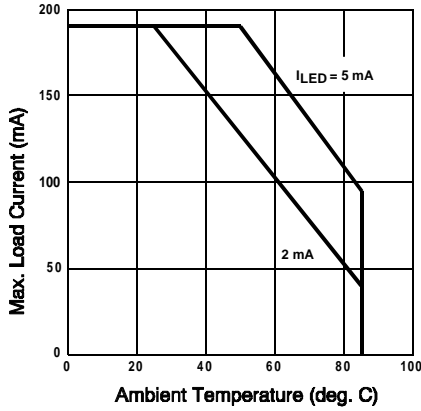## Connection Diagram

International **IGR** Rectifier
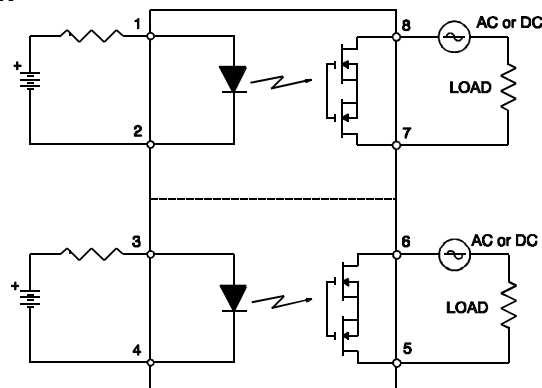
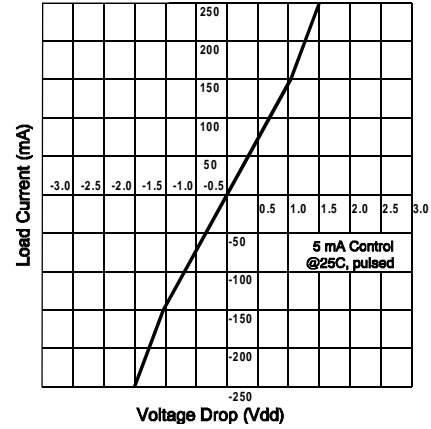**Figure 1. Typical Current Derating Curve**
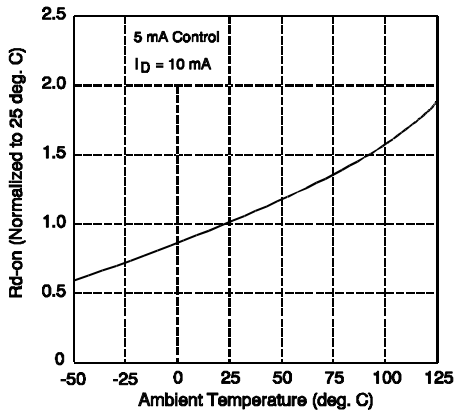
Figure 2. Linearity Characteristics

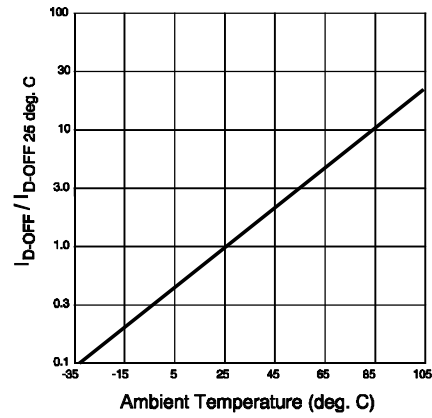**Figure 3. Typical Normalized On-Resistance**

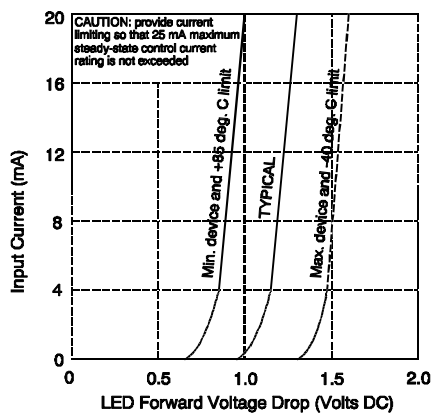**Figure 4. Typical Normalized Off-State Leakage**

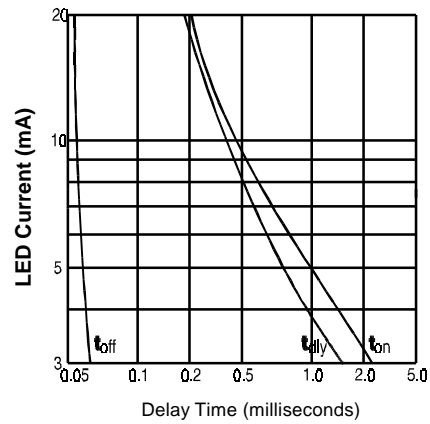**Figure 5. Input Characteristics (Current Controlled)**
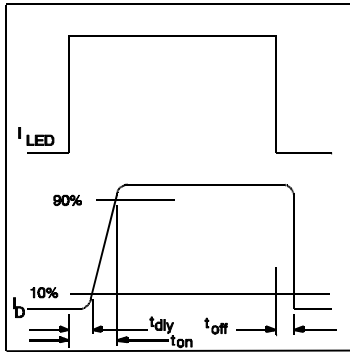
Figure 6. Typical Delay Times

Figure 7. Delay Time Definitions

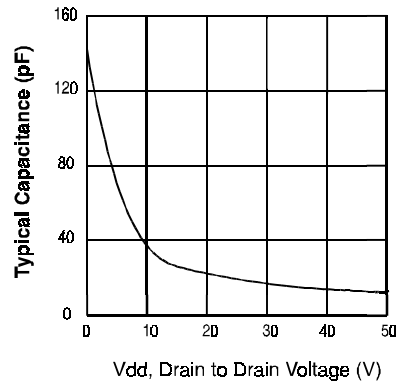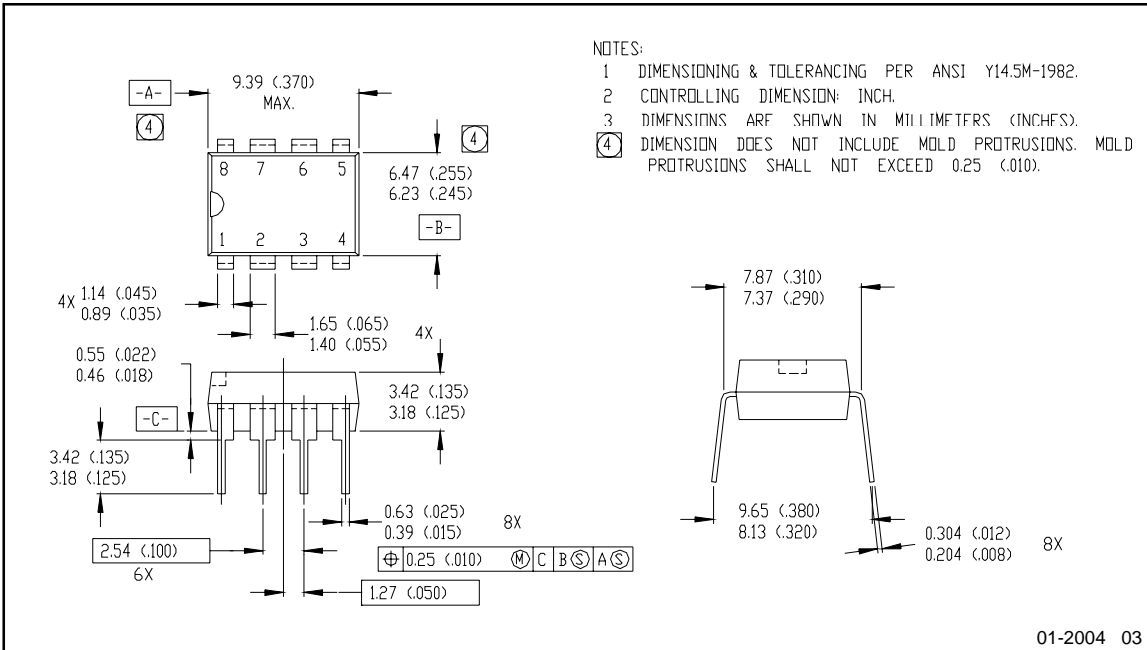**Figure 8. Typical Output Capacitance**

Case Outlines

NOTES:
1 DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2 CONTROLLING DIMENSION: INCH.
3 DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
4 DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD
   PROTRUSIONS SHALL NOT EXCEED 0.25 (.010).

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